

# HZT33

# Monolithic IC Zener Diode for Temperature Compensation

REJ03G1220-0500

(Previous: ADE-208-135D)

Rev.5.00

Jun 23, 2005

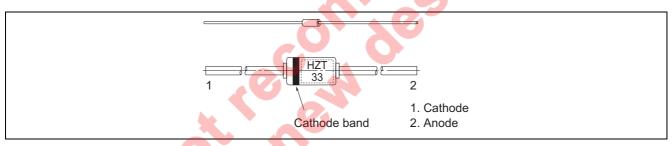
#### **Features**

- Lower temperature coefficient of the reference voltage.
- Lower dynamic resistance.
- High reliability with glass seal.

## **Ordering Information**

Type No.	Cathode band	Mark	Package Name	Package Code (Previous Code)
HZT33	Navy Blue	HZT33	DO-35	GRZZ0002ZB-A (DO-35)

# **Pin Arrangement**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Power dissipation	Pd *	200	mW
Operation temperature	Topr	−20 to +75	°C
Storage temperature	Tstg	-40 to +175	°C

Note: Value at Ta = 75°C.

#### **Electrical Characteristics**

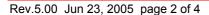
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Zener Voltage	Vz	31.0	_	35.0	V	$I_Z = 5 \text{ mA}$
Dynamic resistance	r <sub>d</sub>	_	_	25.0	Ω	$I_Z = 5 \text{ mA}, f = 1 \text{ KHz}$
Temperature coefficient	γz	_	1.0 * <sup>1</sup>	_	mV/°C	$^{*2}$ I <sub>Z</sub> = 5 mA
						Ta = -20 to +25 to +75°C

Notes: 1. Type Value of  $\gamma_Z$ : 1.0 mV/°C

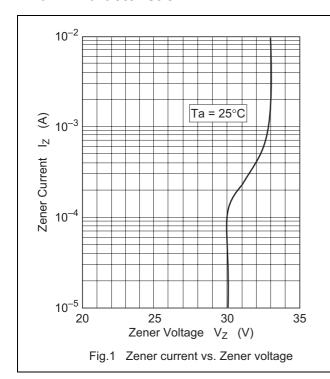
2. Definition of  $\gamma_Z$ 

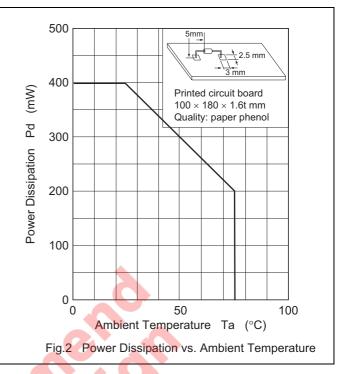
γ<sub>Z</sub> based on Ta = + 25°C and the temperature coefficient with each temperature. (Range of operation temperature)



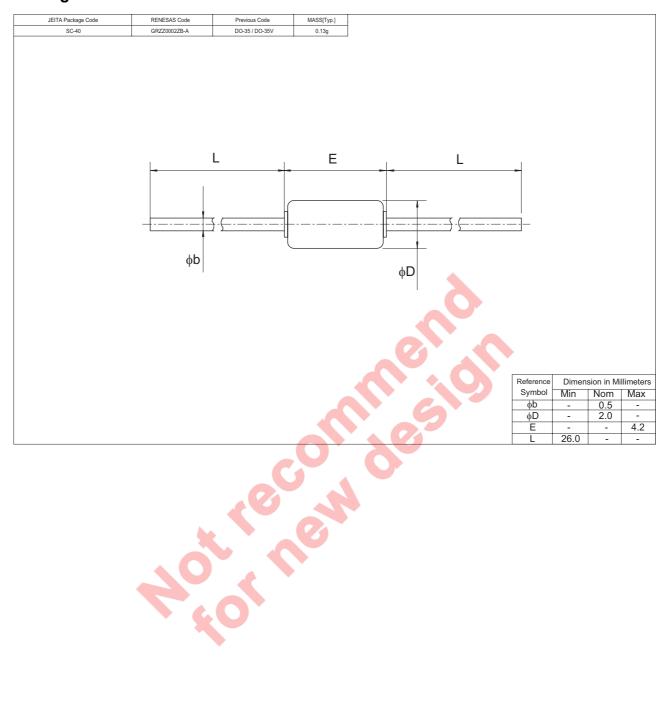


### **Main Characteristic**





# **Package Dimensions**



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